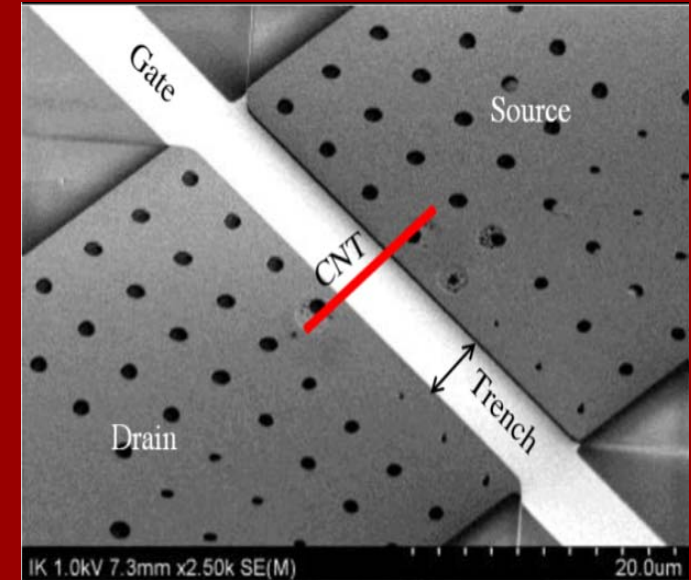
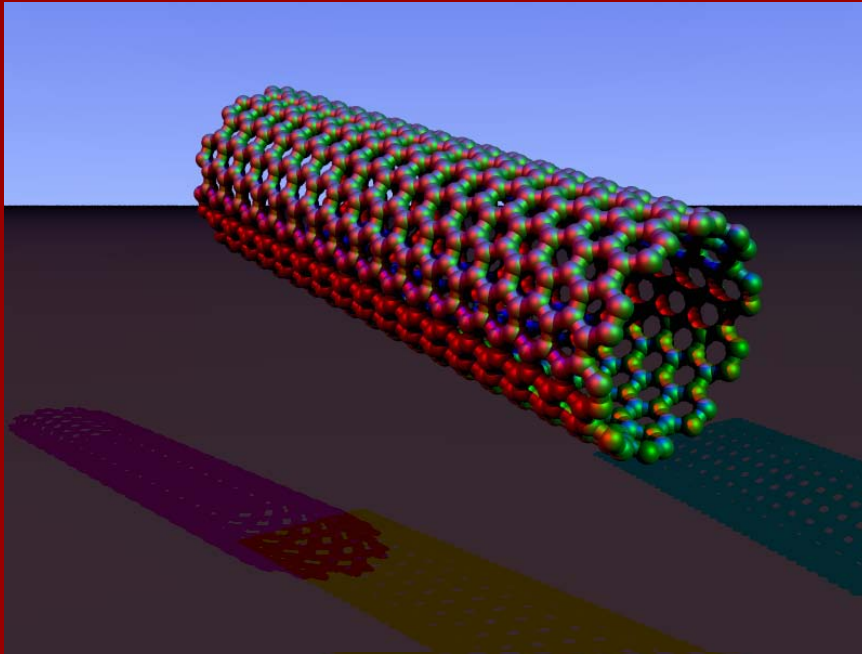


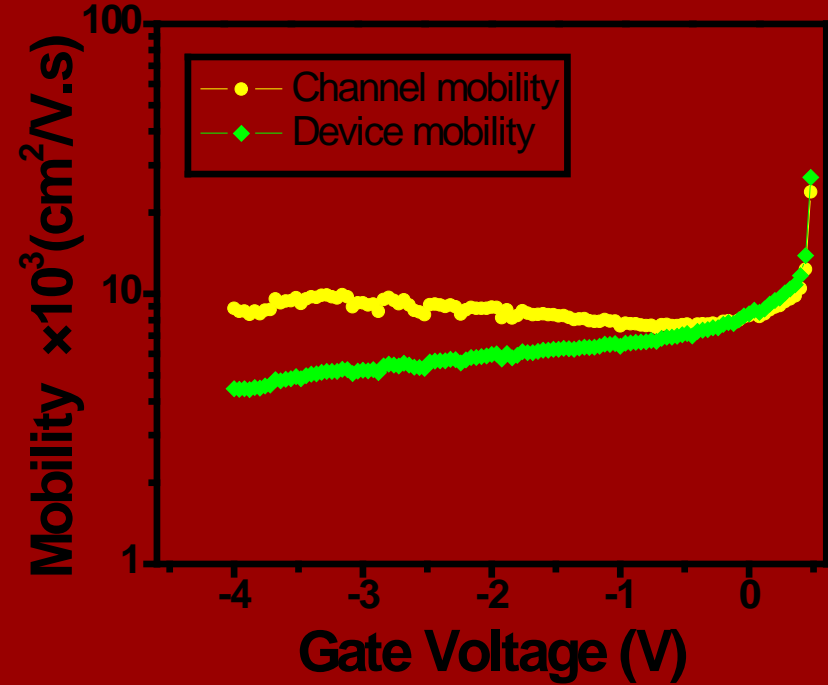
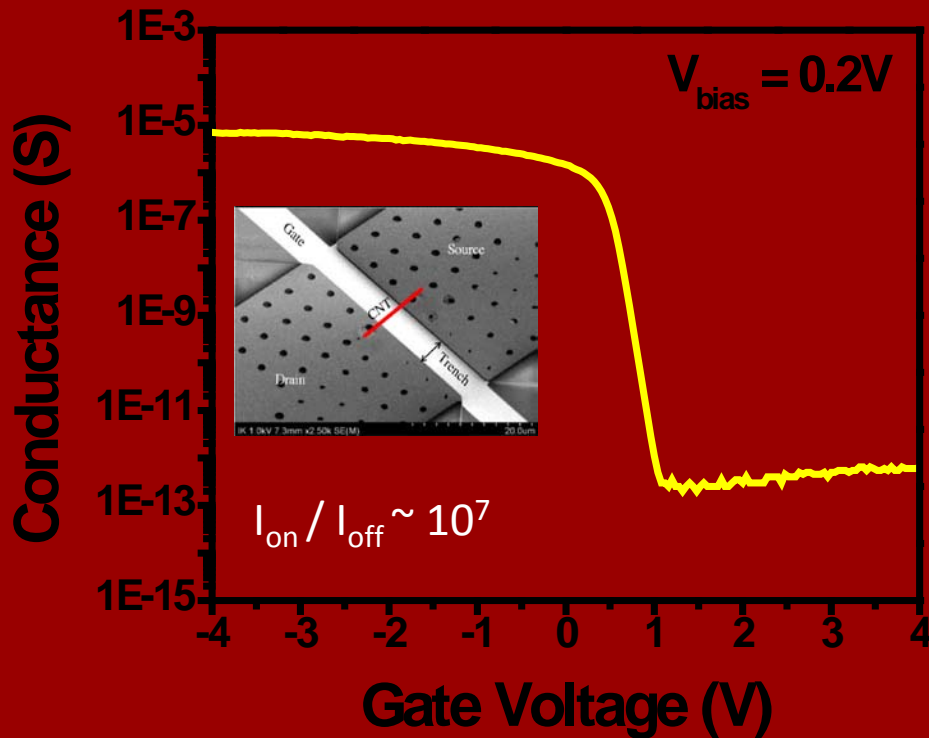
Effect of The Substrate on Metallic Carbon Nanotube Field Effect Transistors

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Carbon Nanotube

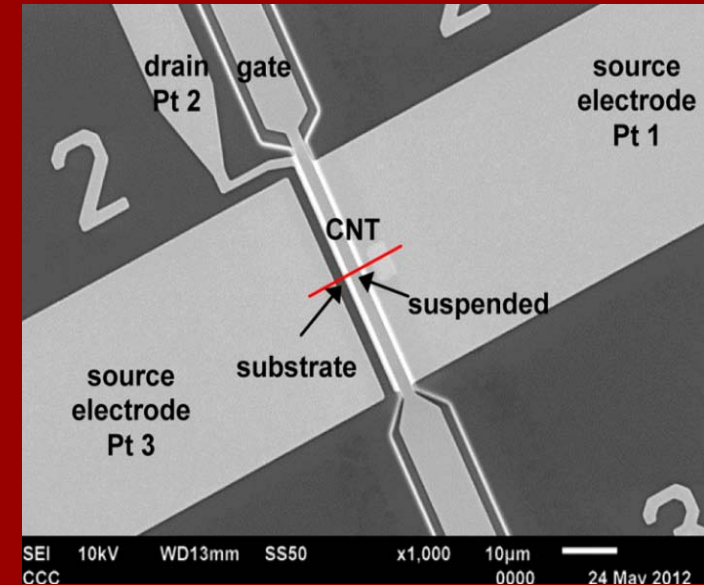
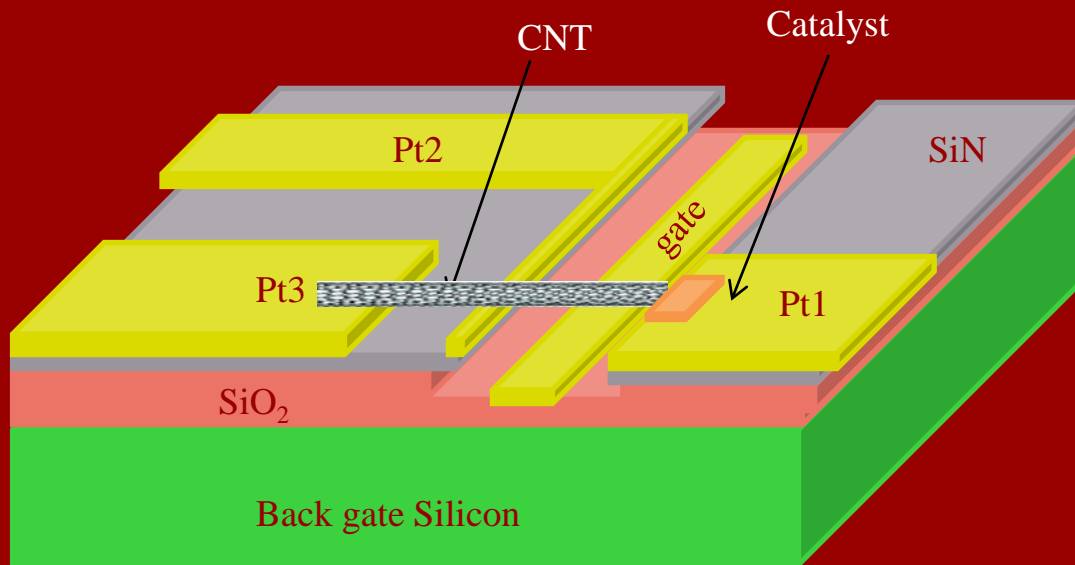


- A rolled sheet of graphene, one single layer of Graphite.
- Metallic or semiconductor.
- Diameter range between 1-3nm and length as high as centimeters.



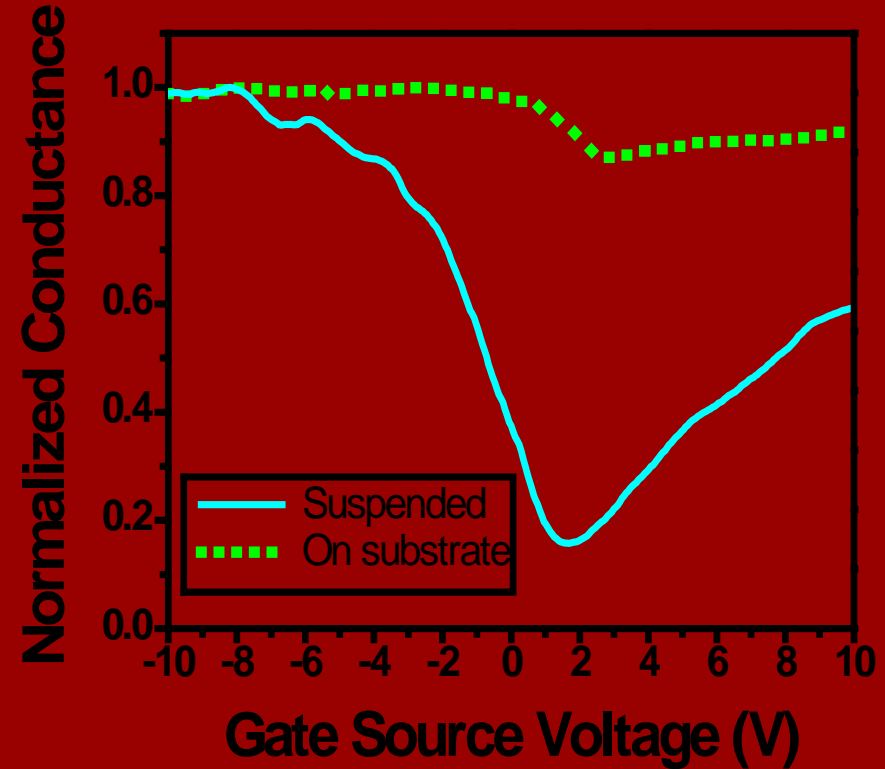
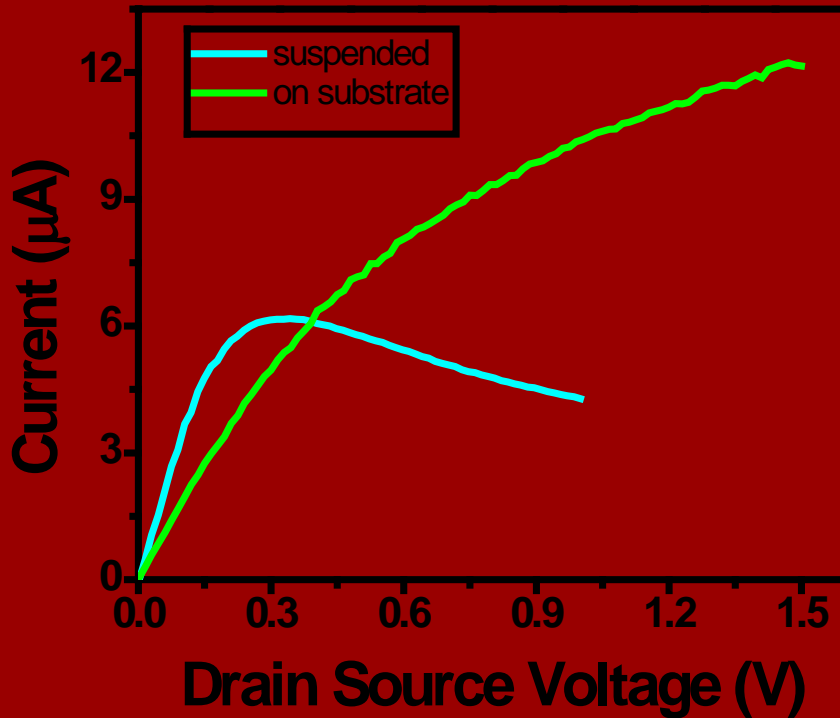
- Suspended semiconducting nanotubes exhibit $I_{\text{on}}/I_{\text{off}}$ as high as 10^7 .
- 2 orders of magnitude larger than what has been reported previously on CNT-FETs and many order of magnitudes larger than MOS devices.
- Channel carrier mobility can reach $10,000 \text{ cm}^2/\text{V}\cdot\text{s}$.

Suspended and on Substrate Supported Metallic CNT-FETs



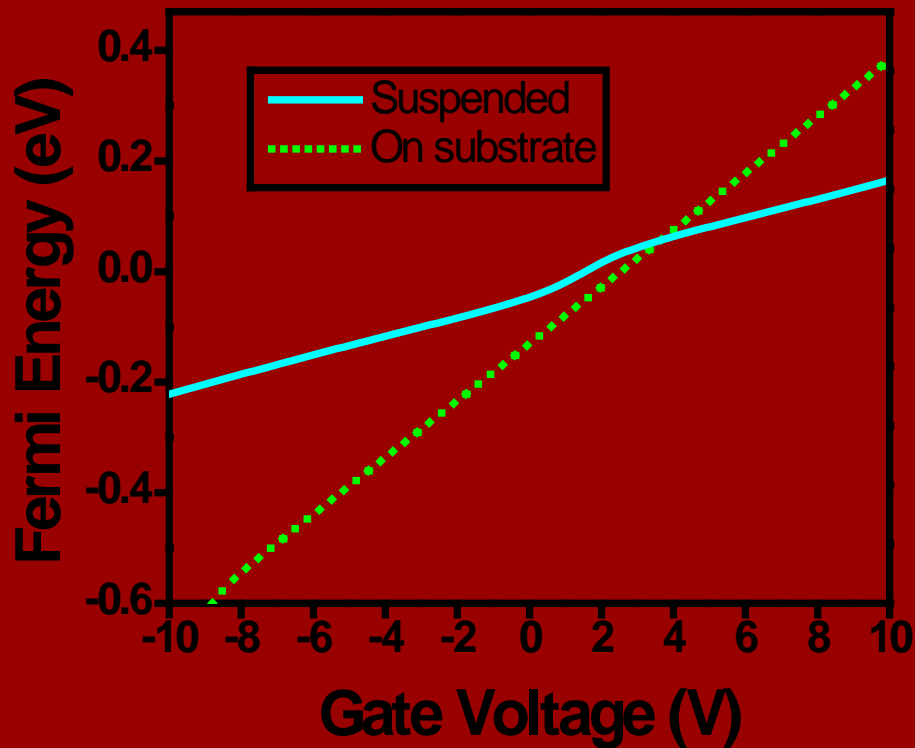
- Compare the changes in the current-voltage characteristics for optimal transistor performance.
- Nanotube devices are fabricated with a suspended portion and on substrate portion.

I_{ds} and I_{gs} of suspended and on Substrate Regions



- When metallic nanotubes are suspended, a large band gap is observed. Conductance varies by 84%.
- the on substrate conductance varies by 11% due to a significant reduction in the band gap caused by supporting the nanotube.

Extracted Fermi Energy



! WARNING

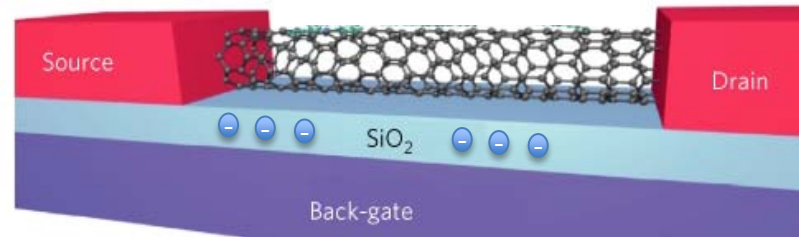
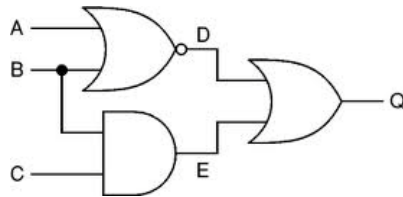
Trapped Charges alter the performance of the nanotube channel by screening out the small band gap

- Fitting the data to the Landauer model (Conductance model) yield band gap energies of 100 meV and 5 meV for the suspended and on Substrate segments, respectively.
- Non linear behavior of the Fermi energy for the suspended segment.
- Almost linear behavior of the Fermi energy for the on-substrate segment.



In Conclusion

- Suspended carbon Nanotubes offer many advantages in electronics due to their high Current on-off states and their high carrier mobility.
- Contrary to popular belief, metallic nanotubes do exhibit a small band gap that can be implemented in a THz or far infrared photodetector.
- Trapped charges can screen out the observation of the band gap for metallic nanotubes.





Thank You

This research is funded by



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